

Docket No. 214391US-2S

IN RE APPLICATION OF: HIDEAKI HATTORI

SERIAL NO: 09/961,284-248

FILED: SEPTEMBER 25 2001

FOR: POWER SEMICONDUCTOR DEVICE AND MANUFACTURING METHOD THEREOF

ASSISTANT COMMISSIONER FOR PATENTS
WASHINGTON, D.C. 20231

SIR:

Transmitted herewith is a **Supplemental Amendment w/ Marked-up Copy** in the above-identified application.

- ☐ **No additional fee is required**
- ☐ Small entity status of this application under 37 C.F.R. §1.9 and §1.27 is claimed.
- ☐ Additional documents filed herewith:

The Fee has been calculated as shown below:

CLAIMS	CLAIMS REMAINING		HIGHEST NUMBER PREVIOUSLY PAID	NO. EXTRA CLAIMS	RATE	CALCULATIONS
TOTAL	40	MINUS	20	20	× \$18 =	\$360.00
INDEPENDENT	3	MINUS	3	0	× \$80 =	\$0.00
		<input type="checkbox"/> MULTIPLE DEPENDENT CLAIMS			+ \$270 =	\$0.00
		TOTAL OF ABOVE CALCULATIONS				\$360.00
		<input type="checkbox"/> Reduction by 50% for filing by Small Entity				\$0.00
		<input type="checkbox"/> Recordation of Assignment			+ \$40 =	\$0.00
		TOTAL				\$360.00

- ☐ A check in the amount of **\$360.00** is attached.
- ☐ Please charge any additional Fees for the papers being filed herewith and for which no check is enclosed herewith, or credit any overpayment to deposit Account No. 15-0030. A duplicate copy of this sheet is enclosed.
- ☐ If these papers are not considered timely filed by the Patent and Trademark Office, then a petition is hereby made under 37 C.F.R. §1.136, and any additional fees required under 37 C.F.R. §1.136 for any necessary extension of time may be charged to Deposit Account No. 15-0030. A duplicate copy of this sheet is enclosed.

Adjusted Fee: 01/07/2002
07/16/2001
01 FC:102
84.00 CR

OBLON, SPIVAK, McCLELLAND,
MAIER & NEUSTADT, P.C.


Gregory J. Maier
Registration No. 25,599

Michael R. Casey, Ph.D.
Registration No. 40,294



22850

Tel. (703) 413-3000
Fax. (703) 413-2220
(OSMMN 10/00)

GJM:MRC:KMB:sy
I:\atty\kmb\214391US\214391.CVR.wpd

RECEIVED
JUN 20 2002
GROUP 3600

RECEIVED
JUN 18 2002
TECHNOLOGY CENTER 2800

RECEIVED
JUN 25 2002
TECHNOLOGY CENTER 2800

214391US-2 S



Suppl
#7/Amot B
7/26/02
V8

IN THE UNITED STATES PATENT & TRADEMARK OFFICE

IN RE APPLICATION OF :

HIDETAKA HATTORI

: EXAMINER: FARAHANI, D.

SERIAL NO: 09/961,284²⁻¹⁸

:

FILED: SEPTEMBER 25, 2001

: GROUP ART UNIT: 2814

FOR: POWER SEMICONDUCTOR :
DEVICE AND MANUFACTURING
METHOD THEREOF

SUPPLEMENTAL AMENDMENT

ASSISTANT COMMISSIONER FOR PATENTS
WASHINGTON, D.C. 20231

SIR:

This is a supplemental response to the amendment filed May 20, 2002. Please amend
the above-identified application as follows:

IN THE CLAIMS

Please amend Claims 1, 2, 5-12, and 15-20 as shown in clean form below.¹

1. (Twice Amended) A power semiconductor device comprising:

a base layer of a first conductivity type;

a base layer of a second conductivity type selectively formed on one surface of said

base layer of the first conductivity type;

06/17/2002 HDERESS1 00000069 09961284

01 FC:103

360.00 OP

RECEIVED

JUN 20 2002

GROUP 3600

¹A marked-up copy of the amended portion of the claims is attached hereto.

cr